

Home Search Collections Journals About Contact us My IOPscience

A new kinetic model for non-equilibrium grain boundary segregation

This article has been downloaded from IOPscience. Please scroll down to see the full text article. 1991 J. Phys.: Condens. Matter 3 609 (http://iopscience.iop.org/0953-8984/3/5/009)

View the table of contents for this issue, or go to the journal homepage for more

Download details: IP Address: 171.66.16.151 The article was downloaded on 11/05/2010 at 07:05

Please note that terms and conditions apply.

## LETTER TO THE EDITOR

## A new kinetic model for non-equilibrium grain boundary segregation

Cai Wei-ping

Material Department, Wuhan Iron and Steel University, Wuhan, Hubei, People's Republic of China

Received 19 March 1990

Abstract. We propose a new kinetic model for non-equilibrium grain boundary segregation. The model is based on three assumptions: that non-equilibrium grain boundary segregation is caused by diffusion of solute-vacancy complexes to the grain boundary; that the grain boundary is a sink for the complexes; and that the grain boundary and grain dimensions are sufficiently large.

Non-equilibrium segregation to grain boundaries and its quantification have been investigated previously [1-5]. Here, a new kinetic model for non-equilibrium grain boundary segregation is advanced, which is based on the following assumptions:

(i) non-equilibrium grain boundary segregation is caused by the diffusion of solutevacancy complexes to the grain boundary;

(ii) the grain boundary is the sink of the complexes;

(iii) the grain boundary is of a certain thickness and grains are large enough.

When an alloy is subjected to solid solution treatment at the temperature  $T_0$ , the solute equilibrium concentration  $C_{gb}$  in the grain boundary can be expressed as [6]

$$C_{\rm gb}(T_{\theta}) = C_{\rm g} \exp(\Delta H/kT_0) \tag{1}$$

where  $C_g$  is the solute concentration in the lattice,  $\Delta H$  is the free energy difference between a solute atom in the lattice and in the grain boundary and k is Boltzmann's constant. In the lattice the equilibrium concentration of the complexes  $C_{c0}$  is given by

$$C_{\rm c0}(T_0) = K_{\rm c}K_{\rm v}C_{\rm g}\exp((E_{\rm b} - E_{\rm f})/kT_0)$$
<sup>(2)</sup>

in which  $K_c$  is a geometrical constant related to complexes,  $K_v$  is another geometrical constant related to vacancies, and  $E_b$  and  $E_f$  are the thermodynamic free energies of vacancy-solute binding and of vacancy formation, respectively. If the alloy cools from  $T_0$  to  $T_1$  instantaneously and is held at  $T_1$ , the diffusion of the complexes in the graingrain boundary will take place (see figure 1). The diffusion equation of the complexes

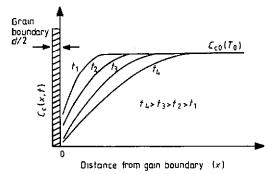


Figure 1. Schematic diagram of the complex concentration change with distance from the grain boundary after different holding times because of the diffusion to the grain boundary. d is the thickness of the grain boundary.

can be written [7]

$$D_{c} \partial^{2} C_{c}(x,t) / \partial x^{2} = \partial C_{c}(x,t) / \partial t$$
(3)

with the restrictions:

$$C_{c}(x = 0, t) = 0$$
  
 $C_{c}(x, t = 0) = C_{c0}(T_{0})$ 

where  $D_c$  is the diffusion coefficient of the complexes,  $C_c(x, t)$  the complex concentration in lattice and t the holding time at  $T_1$ . Equation (3) is the classic diffusion equation. We have the solution

$$C_{\rm c}(x,t) = C_{\rm c0}(T_0) \operatorname{erf}(x/2\sqrt{D_{\rm c}t}).$$
(4)

When the alloy is held at  $T_1$  for the time  $t_1$ , we have

$$\Delta C_{\rm gb}(t_1) = (2/d)N(t_1) \tag{5}$$

in which  $\Delta C_{gb}(t_1)$  is the increment of the solute concentration in the grain boundary due to non-equilibrium segregation after holding time  $t_1$ ; d is the grain boundary thickness and  $N(t_1)$  is the number of complexes diffusing into unit grain boundary area within a holding time  $t_1$ . According to the Fick diffusion equation, equation (5) is changed into

$$\Delta C_{\rm gb}(t_1) = (2D_{\rm c}/d) \int_0^{t_1} \partial C_{\rm c}(x,t)/\partial x|_{x=0} \,\mathrm{d}t. \tag{6}$$

From equation (4) we have

$$\partial C_{\rm c}(x,t)/\partial x|_{x=0} = \bar{C}_{\rm c0}(T_0)/\sqrt{D_{\rm c}t}.$$
(7)

Then

$$\Delta C_{\rm gb}(t_1) = 4\sqrt{D_{\rm c}/\pi} C_{\rm c0}(T_0)\sqrt{t_1/d}$$
(8)

$$C_{\rm gb}(T_1, t) = C_{\rm gb}(T_0) + \Delta C_{\rm gb}(t) \qquad (t < t_{\rm c})$$
(9)

where  $C_{gb}(T_1, t)$  is the solute concentration in the grain boundary at  $T_1$ , and  $t_c$  is the critical holding time; when  $t > t_c$ ,  $C_{gh}$  will be greater than the grain boundary equilibrium concentration and solute atoms in the grain boundary will diffuse back to the grain centre

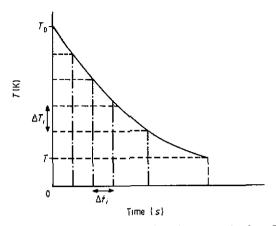


Figure 2. Schematic diagram of continuous cooling from  $T_0$  to T.

during the continuity of complex diffusion to the grain boundary, which means that desegregation occurs.

When the alloy cools continuously from  $T_0$  to T at a rate V(T), we can divide the temperature range and time into N intervals (see figure 2). Each small interval can be considered an isothermal process. For the *i*th interval

$$\Delta_i C_{\rm gb}(T_0 - i\Delta T) = (2/d) \int_0^{\Delta t_i} \partial C_{\rm c}(x,t) / \partial x \big|_{x=0} D_{\rm c}(T_0 - i\Delta T) \,\mathrm{d}t \qquad (10)$$

in which  $D_c(T_0 - i\Delta T)$  is the diffusion coefficient of the complexes at the temperature  $T_0 - i\Delta T$ . So we have the increment of the solute concentration in the grain boundary at the temperature T:

$$\Delta C_{\rm gb}(T) \doteq \sum_{i=1}^{N} \Delta_i C_{\rm gb}(T_0 - i\Delta T) \tag{11}$$

where  $N = (T_0 - T)/\Delta T$ . When  $\Delta t_i \rightarrow 0$ 

$$\lim_{\Delta t_r \to 0} \int_0^{\Delta t_i} \partial C_{\rm c}(x,t) / \partial x |_{x=0} \, \mathrm{d}t = -\partial C_{\rm c}(x,t) / \partial x |_{x=0} \, \mathrm{d}T / V$$

in which dt = -dT/V(T). So

$$\Delta C_{gb}(T) = -\lim_{N \to \infty} \sum_{i=1}^{N} (2D_c/d) \,\partial C_c(x, t) / \partial x \Big|_{x=0} \,\mathrm{d}T/V$$
  
$$= -\int_{T_0}^{T} (2D_c/d) \,\partial C_c(x, t) / \partial x \Big|_{x=0} \,\mathrm{d}T/V$$
  
$$= -\int_{T_0}^{T} (2/d) \sqrt{\frac{D_c}{\pi}} \left( C_{c0}(T_0) / V \right) \,\mathrm{d}T/\sqrt{t}$$
(12a)

## Letter to the Editor

if V(T) is a constant independent of  $T, t = (T_0 - T)/V$  and

$$\Delta C_{gb}(T) = -\left[2C_{c0}(T_0)/(d\sqrt{\pi V})\right] \int_{T_0}^T \sqrt{D_c/(T_0 - T)} \, \mathrm{d}T$$
(12b)

$$C_{\rm gb}(T) = C_{\rm gb}(T_0) + \Delta C_{\rm gb}(T).$$
 (13)

Combining the investigation of rare earth segregation in Al [8], and the related binding energy and solubility data [9], according to equation (9) for the isothermal process and equation (13) for continuous cooling, reasonable agreement between the experimental data and calculated results has been obtained for the non-equilibrium grain boundary segregation of rare earth atoms in aluminium, which we intend to present, in detail, in a later paper.

## References

- [1] Aust KT, Hanneman RE, Niessen P and Westbrook JH 1968 Acta Metall. 16 291
- [2] Williams T M, Stoneham A M and Harries D R 1976 Met. Sci. 10 14
- [3] Harries D R and Marwick A D 1980 Phil. Trans. R. Soc. A 295 197
- [4] Faulkner R G 1981 J. Mater. Sci. 16 373
- [5] Doig P and Flewitt P E J 1981 Acta Metall. 29 1831
- [6] McLean D 1957 Grain Boundaries in Metals (Oxford: Clarendon)
- [7] Verhoeven J D 1975 Fundamentals of Physical Metallurgy (New York: Wiley)

[8] Cai Wei-ping 1990 J. Mater. Sci. submitted

[9] Cai Wei-ping 1990 J. Mater. Sci. submitted

612